

## Product Summary

$V_{(BR)DSS}$	Max $R_{DS(ON)}$	Max $I_D$ $T_A = +25^\circ C$
20V	0.040 $\Omega$ @ $V_{GS} = 4.5V$	5.4A
	0.055 $\Omega$ @ $V_{GS} = 2.5V$	4.6A
	0.075 $\Omega$ @ $V_{GS} = 1.8V$	4.0A

## Description and Applications

This new generation trench MOSFET from Zetex features low on-resistance achievable with low gate drive.

- DC - DC Converters
- Power Management Functions
- Disconnect Switches
- Motor Control

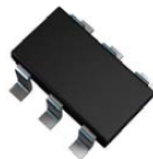
## Features and Benefits

- Low On-resistance
- Fast Switching Speed
- Low Gate Drive Capability
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

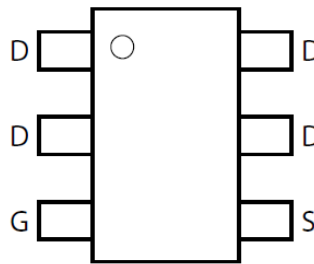
## Mechanical Data

- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208  $\text{\textcircled{3}}$
- Weight: 0.015 grams (Approximate)

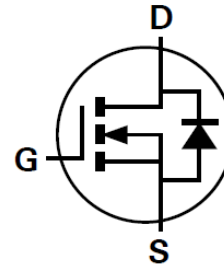
SOT26



Top View



Pinout Top-view



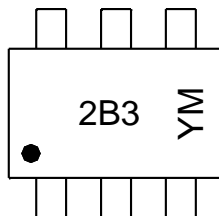
Device Symbol

## Ordering Information (Note 4)

Part Number	Reel Size (inch)	Tape Width (mm)	Quantity Per Reel
ZXMN2B03E6TA	7	8	3000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

## Marking Information



2B3 = Product Type Marking Code  
 YM = Date Code Marking  
 Y or  $\bar{Y}$  = Year (ex: C = 2015)  
 M or  $\bar{M}$  = Month (ex: 9 = September)

### Date Code Key

Year	2015	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025	
Code	C	D	E	F	G	H	I	J	K	L	M	
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

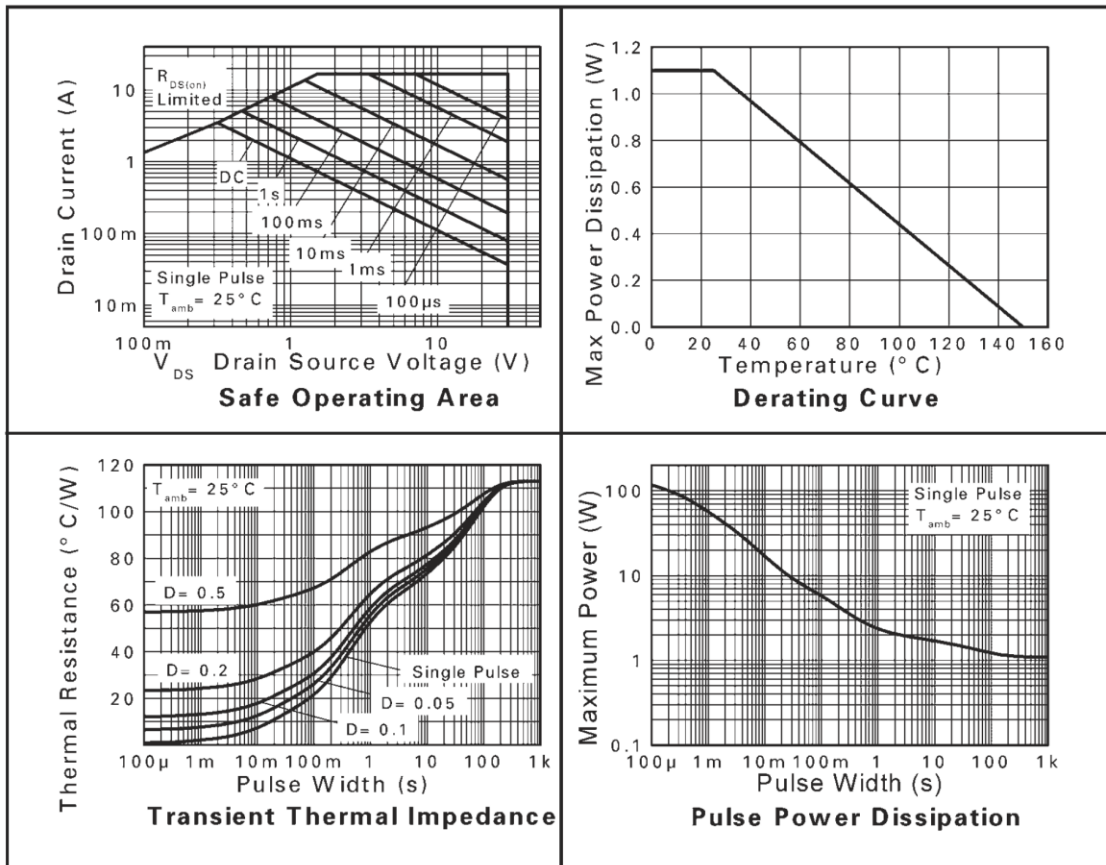
Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		V <sub>DSS</sub>	20	V	
Gate-Source Voltage		V <sub>GS</sub>	±8	V	
Continuous Drain Current	V <sub>GS</sub> = 4.5V	I <sub>D</sub>	T <sub>A</sub> = +25°C (Note 6)	5.4	A
			T <sub>A</sub> = +70°C (Note 6)	4.3	
			T <sub>A</sub> = +25°C (Note 5)	4.3	
Pulsed Drain Current (Note 7)		I <sub>DM</sub>	26	A	
Continuous Source Current (Body Diode) (Note 6)		I <sub>S</sub>	2.8	A	
Pulsed Source Current (Body Diode) (Note 7)		I <sub>SM</sub>	26	A	

**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation at T <sub>A</sub> = +25°C (Note 5)	P <sub>D</sub>	1.1	W
Linear derating factor (Note 5)		8.8	mW/°C
Power Dissipation at T <sub>A</sub> = +25°C (Note 6)	P <sub>D</sub>	1.7	W
Linear derating factor (Note 6)		13.7	mW/°C
Junction to Ambient (Note 5)	R <sub>θJA</sub>	113	°C/W
Junction to Ambient (Note 6)	R <sub>θJA</sub>	73	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

- Notes:
5. For a device surface mounted on 25mm x 25mm FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions.
  6. For a device surface mounted on FR-4 PCB measured at t ≤ 10 secs.
  7. Repetitive rating 25mm x 25mm FR-4 PCB, D = 0.02, pulse width 300µs - pulse width limited by maximum junction temperature.

**Thermal Characteristics**

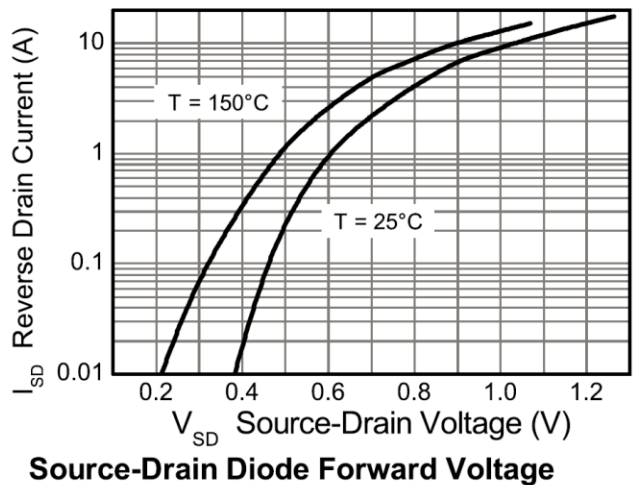
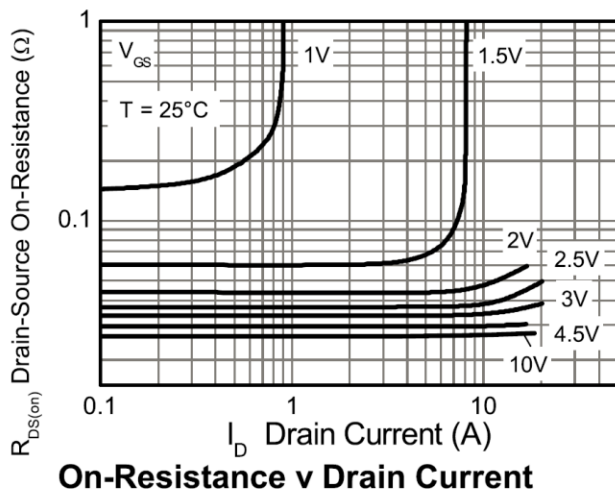
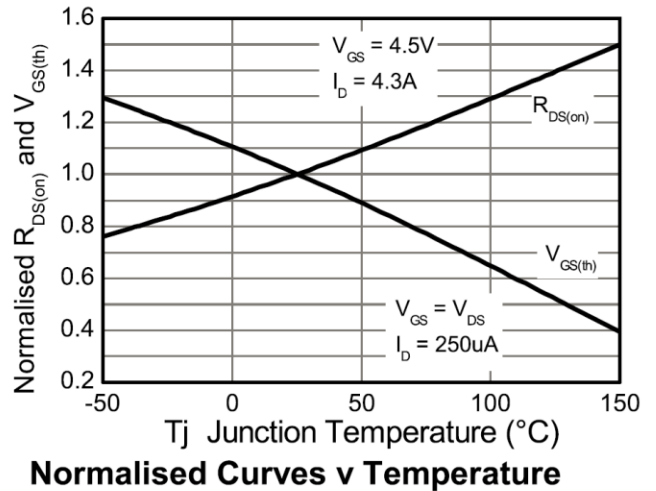
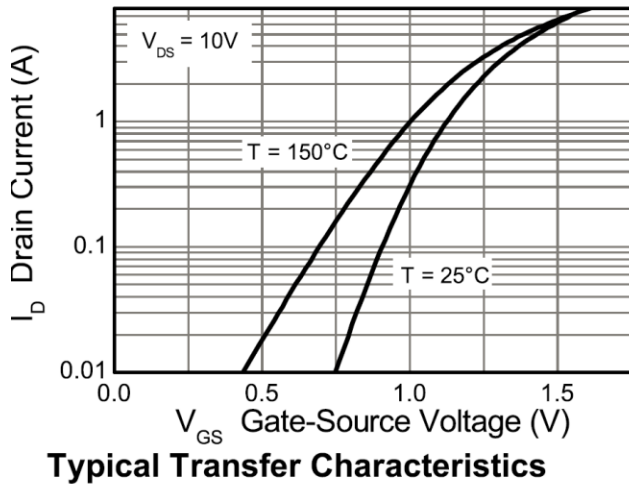
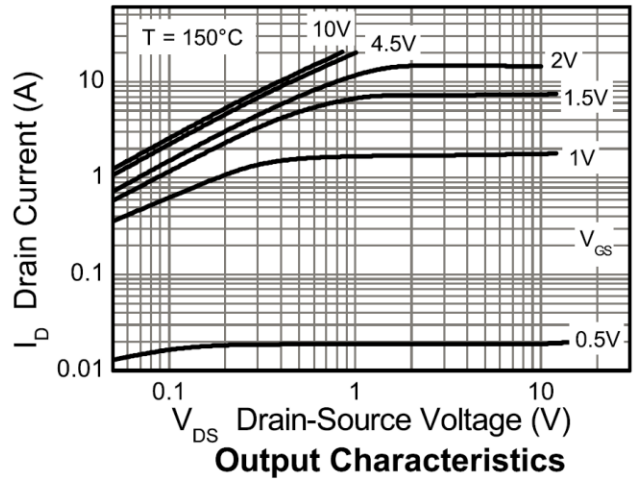
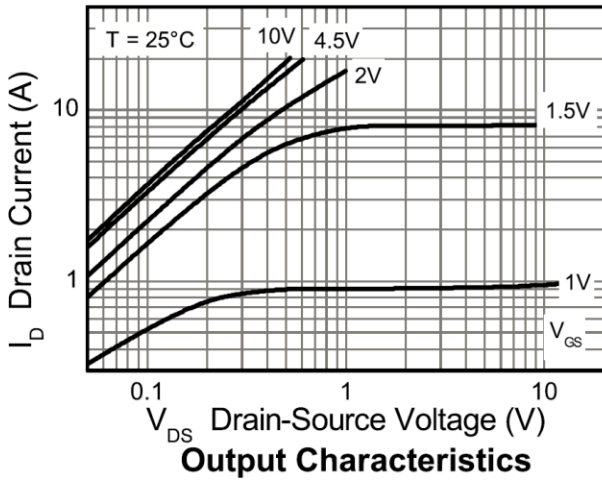


**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

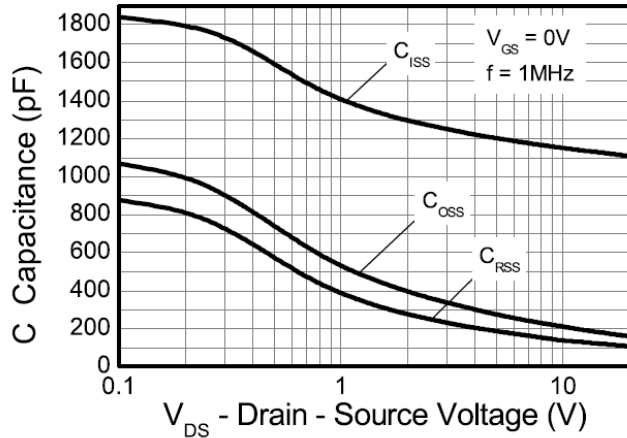
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS</b>						
Drain-source Breakdown Voltage	BV <sub>DSS</sub>	20	—	—	V	I <sub>D</sub> = 250μA, V <sub>GS</sub> = 0V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	—	—	1	μA	V <sub>DS</sub> = 20V, V <sub>GS</sub> = 0V
Gate-body Leakage	I <sub>GSS</sub>	—	—	100	nA	V <sub>GS</sub> = ±8V, V <sub>DS</sub> = 0V
Diode Forward Voltage (Note 8)	V <sub>SD</sub>	—	0.67	0.95	V	T <sub>J</sub> = +25°C, I <sub>S</sub> = 1.8A, V <sub>GS</sub> = 0V
<b>ON CHARACTERISTICS</b>						
Gate-source Threshold Voltage	V <sub>GS(th)</sub>	0.4	—	1.0	V	I <sub>D</sub> = 250μA, V <sub>DS</sub> = V <sub>GS</sub>
Static Drain-source On-state Resistance (Note 8)	R <sub>DS(ON)</sub>	—	—	0.040	Ω	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 4.3A
				0.055		V <sub>GS</sub> = 2.5V, I <sub>D</sub> = 3.7A
				0.075		V <sub>GS</sub> = 1.8V, I <sub>D</sub> = 3.2A
Forward Transconductance (Notes 8 & 10)	g <sub>fs</sub>	—	13.5	—	S	V <sub>DS</sub> = 10V, I <sub>D</sub> = 4.3A
<b>DYNAMIC CHARACTERISTICS</b> (Notes 9 & 10)						
Input Capacitance	C <sub>iSS</sub>	—	1160	—	pF	V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0V f = 1MHz
Output Capacitance	C <sub>oss</sub>	—	210	—	pF	
Reverse Transfer Capacitance	C <sub>rSS</sub>	—	136	—	pF	
Total Gate Charge	Q <sub>g</sub>	—	14.5	—	nC	V <sub>GS</sub> = 4.5V, V <sub>DS</sub> = 10V I <sub>D</sub> = 4.3A
Gate-source Charge	Q <sub>gs</sub>	—	2.0	—	nC	
Gate-drain Charge	Q <sub>gd</sub>	—	2.8	—	nC	
Reverse Recovery Time (Note 10)	t <sub>rr</sub>	—	10.8	—	ns	T <sub>J</sub> = +25°C, I <sub>F</sub> = 2.8A, di/dt = 100A/μs
Reverse Recovery Charge (Note 10)	Q <sub>rr</sub>	—	3.4	—	nC	
Turn-on Delay Time	t <sub>d(on)</sub>	—	2.9	—	ns	V <sub>DD</sub> = 10V, V <sub>GS</sub> = 4.5V I <sub>D</sub> = 1A, R <sub>G</sub> = 6.0Ω
Turn-on Rise Time	t <sub>r</sub>	—	6.4	—	ns	
Turn-off Delay Time	t <sub>d(off)</sub>	—	16.0	—	ns	
Turn-off Fall Time	t <sub>f</sub>	—	11.2	—	ns	

- Notes:
8. Measured under pulsed conditions. Width=300μs. Duty cycle ≤ 2%.
  9. Switching characteristics are independent of operating junction temperature.
  10. For design aid only, not subject to production testing.

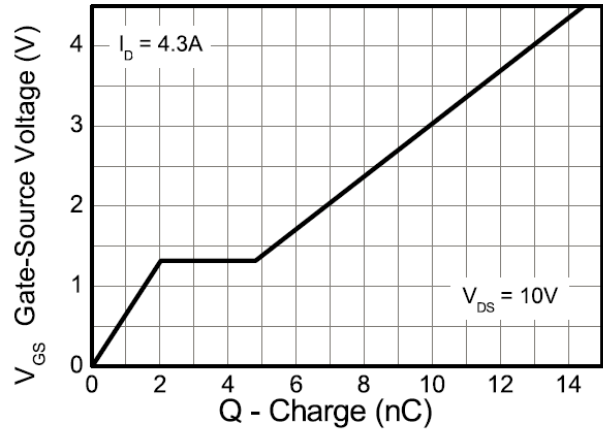
**Typical Characteristics**



**Typical Characteristics (Cont.)**

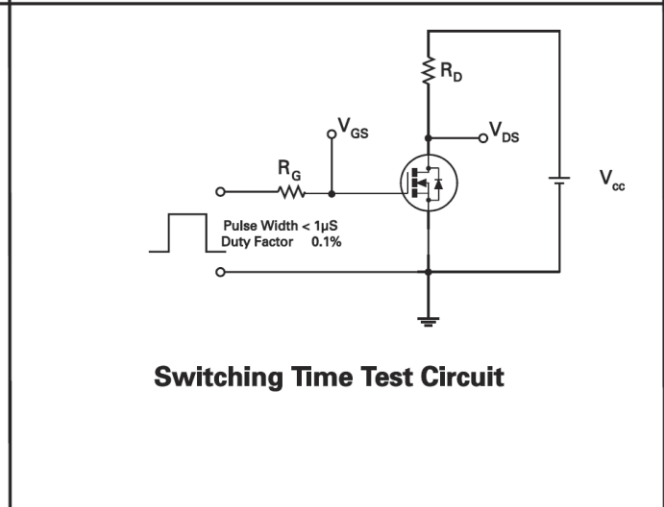
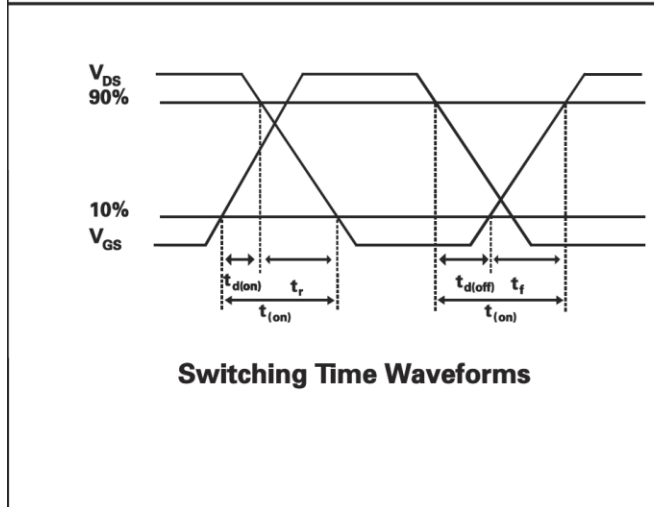
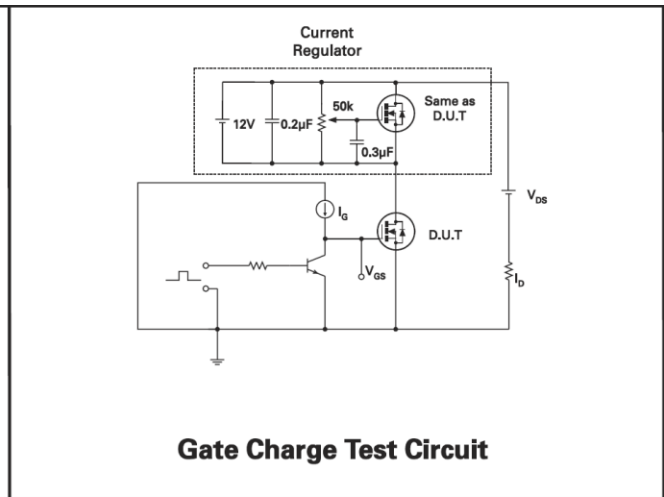
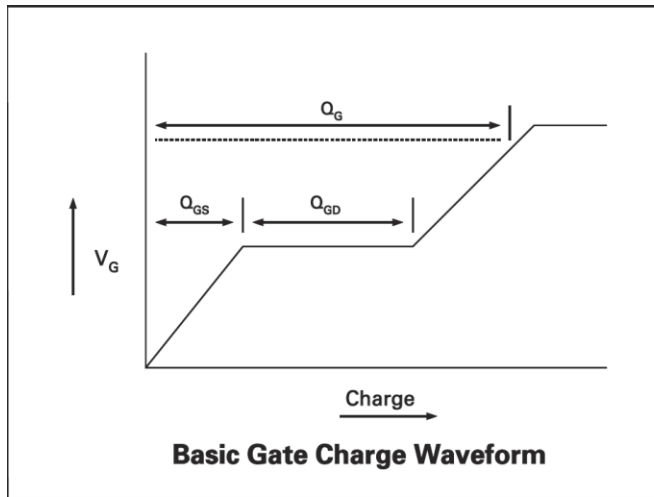


**Capacitance v Drain-Source Voltage**



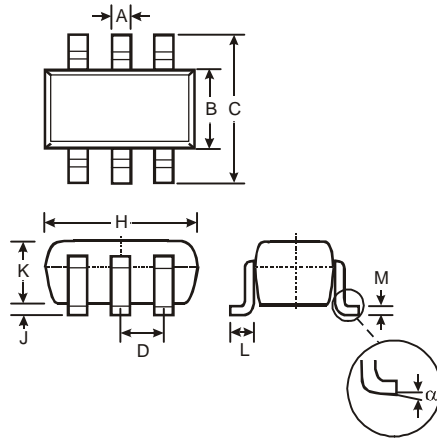
**Gate-Source Voltage v Gate Charge**

**Test Circuits**



**Package Outline Dimensions**

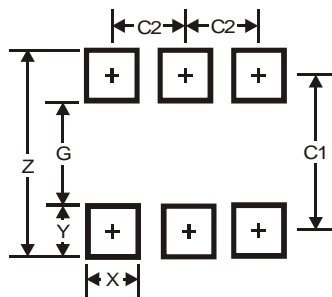
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SOT26			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
α	0°	8°	—
<b>All Dimensions in mm</b>			

**Suggested Pad Layout**

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95

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